

MBR1030CT thru 1060CT

SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - 30 to 60 Volts FORWARD CURRENT - 10 Amperes

FEATURES

- Metal of silicon rectifier,majority carrier conducton
- Guard ring for transient protection
- Low power loss, high efficiency
- High current capability, low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage, high frequency inverters, free whelling, and polarity protection applications

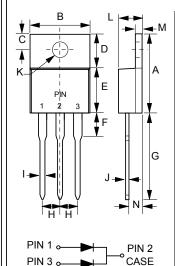
MECHANICAL DATA

Case: TO-220AB molded plastic
Polarity: As marked on the body
Weight: 0.08 ounces, 2.24 grams

• Mounting position : Any

• Max. mounting torque = 0.5 N.m (5.1 Kgf.cm)

TO-220AB



TO-220AB						
DIM.	MIN.	MAX.				
Α	14.22	15.88				
В	9.65	10.67				
С	2.54	3.43				
D	5.84	6.86				
E	8.26	9.28				
F	-	6.35				
G	12.70	14.73				
Н	2.29	2.79				
ı	0.51	1.14				
J	0.30	0.64				
K	3.53 Ø	4.09 Ø				
L	3.56	4.83				
М	1.14	1.40				
N	2.03	2.92				
All Dimensions in millimeter						

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

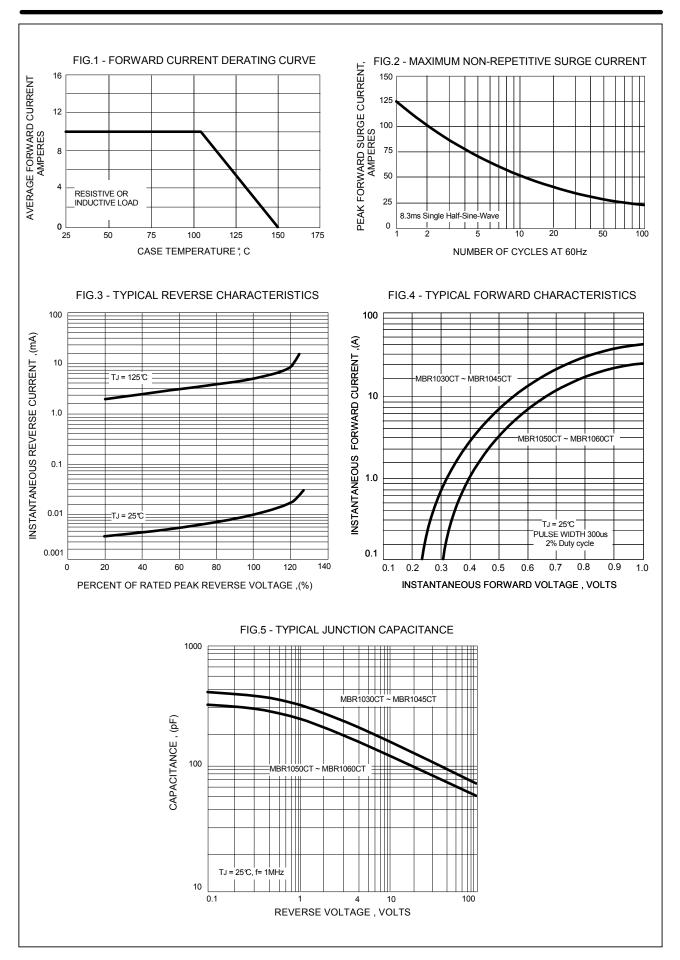
CHARACTERISTICS	SYMBOL	MBR 1030CT	MBR 1035CT	MBR 1040CT	MBR 1045CT	MBR 1050CT	MBR 1060CT	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	30	35	40	45	50	60	V
Maximum RMS Voltage	VRMS	21	24.5	28	31.5	35	42	V
Maximum DC Blocking Voltage	VDC	30	35	40	45	50	60	V
Maximum Average Forward RectifiedCurrent at TC=105°C (See Fig.1)	l(AV)	10						А
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	IFSM	125						А
Voltage Rate of Change (Rated VR)	dv/dt	10000						V/us
Maximum Forward Voltage, (Note 1) @IF=5A TJ=125℃ @IF=5A TJ=25℃ @IF=5A TJ=25℃ @IF=10A TJ=125℃	VF	0.57 0.65 0.70 0.80 0.84 0.90					80	V
Maximum DC Reverse Current @TJ =25℃ at Rated DC Blocking Voltage @TJ =125℃	lR	0.1 15						mA
Typical Junction Capacitance, per element (Note 2)	Cı		17	70		2	20	pF
Typical Thermal Resistance (Note 3)	Rejc	3.0					°C/W	
Operating Temperature Range	TJ	-55 to +150					°C	
Storage Temperature Range	Tstg	-55 to +175						°C
						DEV 2 0-	+ 2010 I/TH	040

NOTES: 1.300us Pulse Width, 2% Duty Cycle.

- 2. Thermal Resistance Junction to Case.
- 3. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

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